

SPECIFICATIONS:

1. TEMP. CLASS: 105° C.
2. INDUCTANCE: @ 10 KHZ, 0.1 V
(1-3) = 225 μ Hy MIN.
3. LEAKAGE INDUCTANCE: @ 100 KHZ, 1 VOLT
WITH (4-6) SHORTED
(1-3) = 0.7 μ Hy MAX.
4. INTERWINDING CAPACITANCE: @ 100 KHz
(1-3) TO (4-6) = 2.0 pF MAX. WITH SHIELD GROUNDED.
5. TURNS RATIO: (1-3):(4-6) = 1:1.22 \pm 2 %
6. DCR: (1-3), (4-6) = 0.1 • NOM.
7. THIS TRANSFORMER IS DESIGNED TO OPERATE WITH CRYSTAL SEMICONDUCTOR CS8401.8402, 8411, & 8412
8. HIPOT 1500 VAC

